



### LOW CAPACITANCE BIDIRECTIONAL TVS DIODE

## **Product Summary**

VBR Min	IPP Max	Сін тур
6V	4A	0.21pF

## **Description**

This new generation TVS is designed to protect sensitive electronics from the damage due to ESD. The combination of small size and high ESD surge capability makes it ideal for use in portable applications such as USB3.1 and Thunderbolt3.

## **Applications**

- USB3.1
- Thunderbolt3
- Computers and Peripheral

### **Features**

- Provides ESD Protection per IEC 61000-4-2 Standard: Contact ±10kV
- 1 Channel of ESD Protection
- Low Channel Input Capacitance
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- For automotive applications requiring specific change control (i.e. parts qualified to AEC-Q100/101/200, PPAP capable, and manufactured in IATF 16949 certified facilities), please contact us or your local Diodes representative. https://www.diodes.com/quality/product-definitions/

### **Mechanical Data**

Case: X2-DSN0603-2

Case Material: Chip Scale Package

Moisture Sensitivity: Level 1 per J-STD-020

 Terminals: NiAu Bump. Solderable per MIL-STD-202, Method 208

Weight: 0.0002 grams (Approximate)

### X2-DSN0603-2



Top View

**Bottom View** 



**Device Schematic** 

## Ordering Information (Note 4)

1					
Part Number	Compliance	Marking	Reel Size (inches)	Tape Width (mm)	Quantity per Reel
DESD5V0X1BCSF-7	Standard	8K	7	8	10.000/Tape & Reel

Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.
- 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

## **Marking Information**



8K = Product Type Marking Code Bar Denotes Pin 1



# **Maximum Ratings** (@ $T_A = +25^{\circ}C$ , unless otherwise specified.)

Characteristic	Symbol	Value	Unit	Conditions
Peak Pulse Power Dissipation	P <sub>PP</sub>	24	W	8/20µs, per Figure 3
Peak Pulse Current	I <sub>PP</sub>	4	Α	8/20µs, per Figure 3
ESD Protection – Contact Discharge	Vesd_contact	±10	kV	IEC 61000-4-2 Standard

## **Thermal Characteristics**

Characteristic	Symbol	Value	Unit
Package Power Dissipation (Note 5)	P <sub>D</sub>	250	mW
Thermal Resistance, Junction to Ambient (Note 5)	Reja	500	°C/W
Operating and Storage Temperature Range	TJ, TSTG	-55 to +150	°C

# **Electrical Characteristics** (@TA = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Conditions
Reverse Standoff Voltage	$V_{RWM}$	_	_	5.0	V	_
Channel Leakage Current (Note 6)	I <sub>RM</sub>	_	_	1	μA	VRWM = 5V
		_	6.0	_		IPP = 4A, tP = 8/20µs
Clamping Voltage	$V_{CL}$	_	6.0	_	V	I <sub>PP</sub> = 8A,TLP, t <sub>P</sub> = 100ns
		_	9.0	_		IPP = 16A,TLP, tP = 100ns
Breakdown Voltage	V <sub>BR</sub>	6	_	9	V	I <sub>R</sub> = 1mA
Differential Resistance	RDYN	_	0.35	_	Ω	TLP, 10A, t <sub>P</sub> = 100ns
Channel Input Capacitance	Cin	_	0.21	_	pF	V <sub>R</sub> = 0V, f = 1MHz

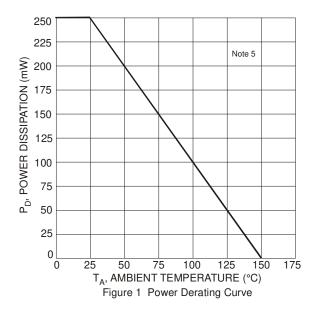
Notes:

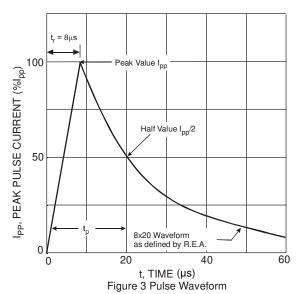
<sup>5.</sup> Device mounted on FR-4 PCB pad layout (2oz copper) as shown on Diodes Incorporated's suggested pad layout, which can be found on our website at http://www.diodes.com/package-outlines.html.

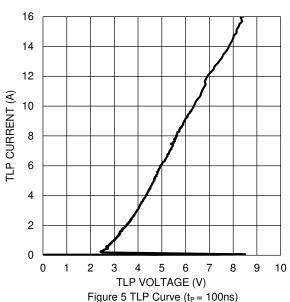
<sup>6.</sup> Short duration pulse test used to minimize self-heating effect.

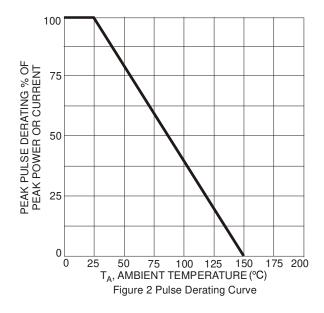


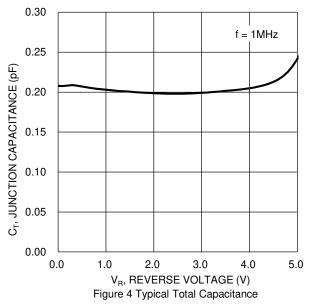










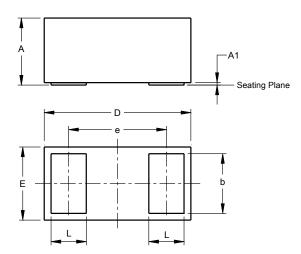




# **Package Outline Dimensions**

Please see http://www.diodes.com/package-outlines.html for the latest version.

### X2-DSN0603-2



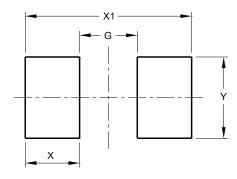
X2-DSN0603-2					
Dim	Min	Max	Тур		
Α	0.280	0.320	0.300		
A1	0.00	0.020	0.010		
b	0.220	0.260	0.240		
D	0.575	0.625	0.600		
Е	0.275	0.325	0.300		
е	-	-	0.400		
L	0.120	0.160	0.140		
All Dimensions in mm					

Note 7. Device side walls are electrically active bare silicon. Avoid contact of solder or flux on the side walls during the PCB assembly process.

# **Suggested Pad Layout**

Please see http://www.diodes.com/package-outlines.html for the latest version.

### X2-DSN0603-2



Dimensions	Value (in mm)
G	0.206
Х	0.194
Υ	0.291
X1	0.594



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